Amendments to the Claims:

This listing of claims will replace all prior versions, and listings, of claims in the application:

Listing of Claims:

Claims 1-12 (withdrawn)

- Claim 13 (currently amended): A light emitting diode having a plated substrate with a mirror, comprising:
 - an LED epitaxial structure sequentially comprising a second cladding layer, an active layer, a first cladding layer, a window and a metal contact layer, wherein said second cladding layer is partially exposed;
 - a first electrode formed on said metal contact layer;
 - a second electrode formed on said exposed second cladding layer;
 - a mirror formed beneath said LED epitaxial structure; and
 - a permanent metal substrate plated beneath said mirror-after completing the first and second electrodes and retaining sawing streets without plating the substrate thereon;
 - wherein said mirror is made from a composite, a metal or an alloy selected from the group consisting of:
 - Al/MgF₂, Pt/Al₂O₃, Pt/SiO₂, Pt/MgF₂, Au/SiO₂, Au/MgF₂, Ag/MgF₂;
 - Ag, Au, Au/Zn, Au/Be, Au/Ge, Au/Ge/Ni and Zn, or mixtures thereof when said LED epitaxial structure is made from (Al_xGa_{1-x})_yIn_{1-y}P;
 - Ag, Pt, Pd, Al, and Ni, or mixtures thereof when said LED epitaxial structure is made from $Ga_xAl_vIn_{1-x-v}N$, $0 \le x \le 1$, $0 \le y \le 1$;
 - Ag, Au, Au/Zn, Au/Be, Au/Ge, Au/Ge/Ni and Zn, or mixtures thereof when said LED epitaxial structure is made from $In_xGa_{1-x}As$, $0 \le x \le 1$, $0 \le y \le 1$; or
 - Ag, Pt, Pd, Au/Zn, Au/Be, Au/Ge, Au/Ge/Ni, Al and Ni, or mixtures thereof when said LED epitaxial structure is made from ZnS_xSe_{1-x} , $0 \le x \le 1$, $0 \le y \le 1$.

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Claim 14 (canceled)

Claim 15 (original): The light emitting diode as claimed in claim 13 further comprising a transparent conductive film between said first electrode and said metal contact layer.

Claims 16-25 (canceled)